

☐ Pending

☐ Active

- ☒ L13: (3381) ((438/301) or (438/302) or (438/303) or (438/304) or (438/305) or (438/306) or (438/...
- ☒ L14: (743) LDMOS or "lateral double diffused metal oxide semiconductor" or "lateral double-diffu...
- ☒ L15: (1416) RSD or "reduced surface drain" or "reduced-surface-drain"
- ☒ L16: (9) (LDMOS or "lateral double diffused metal oxide semiconductor" or "lateral double-diffus...
- ☒ L17: (1) (((438/301) or (438/302) or (438/303) or (438/304) or (438/305) or (438/306) or (438/30...
- ☒ L18: (9) 13 and 15
- ☒ L19: (34) 13 and 14
- ☒ L20: (3404420) @ad<20010821
- ☒ L21: (28) 19 and 20
- ☒ L23: (1160) (implant or implants or implanted or implanting or implantation) with (heat or heats...
- ☒ L24: (204) 13 and 23
- ☒ L25: (1) 21 and 24
- ☒ L26: (911) 23 and 20
- ☒ L27: (9) 15 and 16
- ☒ L28: (0) 26 and 27

☐ Failed

☐ Saved

☐ Favorites

Screen Up Browse Queue

DBs USPA Plurals

Default operator Highlight all hit terms initially

20 and 24

BRG BAR Image Text HTML

	U	I	Document	Issue Da	Pag	Title	Current	Current X	Retrieval	Inventor	S	C	P	2	3
1	<input type="checkbox"/>	<input type="checkbox"/>	US200300	2003020	16	Method for manufacturing a	438/306	257/E290		Imain, Mohamed et al.	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
2	<input type="checkbox"/>	<input type="checkbox"/>	US200200	2002061	5	Method of forming gate stru	438/305	257/E212		Chen, Wei Wen	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>

Hit Details HTML

Ready

NUM